

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| L10 | 97 | 257/197.ccls. and ((back or backside) with (gate or electrode or conductor or contact)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 11:07 |
| L11 | 206 | (257/526).ccls. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 11:10 |
| L12 | 178 | 257/565.ccls. and ((inversion or charge) with (layer or region)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 11:22 |
| L14 | 1625 | (257/587 or 257/592).ccls. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 11:49 |
| L15 | 5 | (257/587 or 257/592).ccls. and (back near2 gate or backgate) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 11:49 |
| L16 | 142 | (257/E29.171,E29.183,E29.189,E29.19,E29.198).ccls. and ((back near4 (electrode or gate or conductor)) or backgate) | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2007/01/22 11:55 |
| L17 | 224 | semiconductor and ((back\$4 or buried) with (gate or electrode)) and inversion and (vertical\$5 with bipolar) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 12:01 |
| L18 | 219 | semiconductor and (((back or buried) with (gate or electrode)) or backgate) and inversion and (vertical\$5 with bipolar) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 12:02 |

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|-----|------|---|---|----|----|------------------|
| L19 | 1468 | semiconductor and (((back or buried) with (gate or electrode)) or backgate) and inversion and (bipolar) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 12:03 |
| L20 | 195 | semiconductor and (((back or buried) with (gate or electrode)) or backgate) and (inversion or accumulat\$5) and (vertical\$4 near5 bipolar) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 12:02 |
| L21 | 16 | semiconductor and (((back or buried) with (gate or electrode)) or backgate) and inversion and (bipolar) and (collector with intrinsic) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/01/22 12:03 |